

ANSWER KEY > Material Science

1. (c)	6. (c)	11. (a)	16. (d)	21. (d)
2. (a)	7. (c)	12. (d)	17. (c)	22. (c)
3. (d)	8. (a)	13. (b)	18. (d)	23. (a)
4. (d)	9. (a)	14. (b)	19. (d)	24. (c)
5. (a)	10. (b)	15. (a)	20. (b)	25. (c)

DETAILED EXPLANATIONS

- (c)

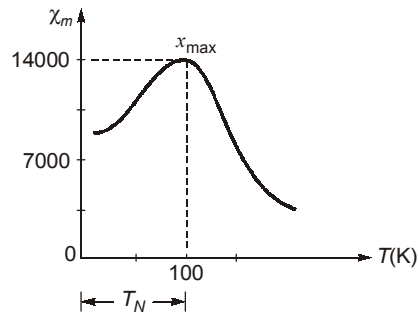
Ferrites exhibit hysteresis during magnetization. The hysteresis loops of Cu-Mn ferrite, Mg-Mn ferrite and Zn-Mn ferrite are square, and they are used as memory cores in computers.
- (a)

Ferrites have following properties:

 - High electrical resistivities.
 - Low power loss at high frequencies.
 - Suitable for temporary as well as permanent magnetic application due to their spontaneous magnetization.
 - Conductivity behaviour like those of semiconductors.
 - Hysteresis loop is almost rectangular.

Hence, statements 1, 4 and 5 are correct.

3. (d)



At Neel temperature (T_N), susceptibility (χ_m) is maximum.

4. (d)

Clausius Mossotti equation is valid for Lorentz internal field only and for Lorentz internal field,

internal field constant is $\gamma = \frac{1}{3}$.

5. (a)

$$\text{Uniaxial stress } (P) = \gamma \cdot \frac{\Delta C}{C}$$

$$q = CV$$

$$\Rightarrow \text{Polarization, } P = \frac{q}{A} = \frac{C}{A} \cdot V$$

Where A is area of the crystal capacitor.

$$\therefore \Delta P = \left(\frac{V}{A} \right) \times \Delta C$$

$$\Rightarrow \frac{\Delta P}{P} = \frac{\Delta C}{C}$$

$$\Rightarrow \text{Stress } (P) = \gamma \cdot \frac{\Delta P}{P} = \frac{130 \times 20}{500} = 5.2 \text{ GPa}$$

6. (c)

Both the given statements are correct.

7. (c)

Secondary or molecular bonds are either ion-dipole interaction, dipole-dipole interaction or vanderwalls are weaker than primary bonds (ionic, covalent).

8. (a)

Graphene consists of a monolayer of a 2 D lattice of sp^2 bonded carbon.

10. (b)

Total flux density is given by:

$$\vec{B} = \mu_0 \vec{H} + \mu_0 \vec{M}$$

$\mu_0 \vec{M}$ = flux density due to magnetization

$\mu_0 \vec{H}$ = flux density due to applied field

11. (a)

- Polarization of a pyroelectric material changes on heating.
- Every pyroelectric material is piezoelectric material but converse is not true.

15. (a)

The dielectric constant ϵ_r (or relative permittivity) is a measure of polarization of dielectric materials. Dielectric strength is the voltage per unit thickness that can be sustained by an insulating material before its breakdown. A good insulating material or a dielectric material should have high value of dielectric strength but low value of dielectric constant (ϵ_r).

16. (d)

Space charge polarization occurs due to the accumulation of charges at the electrodes or at the interfaces in a multi-phase material.

17. (c)

In the presence of dielectric,

$$D = (\epsilon_0 E + P) = (\epsilon_0 E + \epsilon_0 \nu_e E)$$

18. (d)

- A diamagnetic material does not obey Curie's law.
- Paramagnetic material obeys Curie's law i.e. susceptibility of a paramagnetic material is inversely proportional to temperature.

$$\chi_m \propto \frac{1}{T}$$

or, $\chi_m T = \text{Constant}$

- A ferromagnetic material is strongly attracted by a magnet.
- In antiferromagnetic materials the permanent dipoles tend to align themselves so that alternate dipoles are antiparallel to the applied field. The result is a cancellation of the effects of each dipole and a zero net increase in flux density in the material. Hence, the permanent dipole moment is zero in these materials.

20. (b)

Option (a) is Debye's generalisation of Claussius-Mosotti's equation and only applicable for gases.

21. (d)

The intercepts C_1 (along x -axis) = a ,

C_2 (along y -axis) = $b/2$,

and C_3 (along z -axis) = $3c$

Therefore, $p = \frac{c_1}{a} = \frac{a}{a} = 1$

$$q = \frac{c_2}{b} = \frac{b/2}{b} = \frac{1}{2}$$

and $r = \frac{c_3}{c} = \frac{3c}{c} = 3$

$$\therefore h = \frac{1}{p} = \frac{1}{1} = 1$$

$$k = \frac{1}{q} = \frac{1}{1/2} = 2$$

and $l = \frac{1}{r} = \frac{1}{3}$

$$\begin{aligned} \text{Hence, } (h, k, l) &= \left(1, 2, \frac{1}{3}\right) = \frac{1}{3}(3, 6, 1) \\ &= (3, 6, 1) \end{aligned}$$

(Since Miller indices is always an integer)

23. (a)

The bond that is formed between water molecules due to attraction between the positively charged hydrogen end of a molecule and the negatively charged oxygen end of another molecule is called the hydrogen bond.

The strength of various bonds in increasing order are as follows:

Vander walls bonds < Hydrogen bonds < Ionic bonds < Metallic bonds < Covalent bonds.

24. (c)

It is not due to cooperative effect among domains.

25. (c)

When many unit cells repeat in a three-dimensional space, a crystal is obtained. The structure of a crystal is same as that of a repeating unit cell.

